# NSN 5961-01-276-2456

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AeroBase Group

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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.550 inches

## **Overall Height:**

Between 0.250 inches and 0.300 inches

# **Overall Width:**

1.050 inches

## **Mounting Facility Quantity:**

2

# Internal Configuration:

## Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-204aa

Electrode Internally-electrically Connected To Case:

# Drain

Mounting Method:

Unthreaded hole

## Features Provided:

Electrostatic sensitive

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

2.0 gate to source threshold voltage and 4.5 gate to source threshold voltage

#### **Current Rating Per Characteristic:**

500.00 nanoamperes zero-gate-voltage source current watts and 250.00 microamperes zero-gate-voltage source current megawatts

# Maximum Operating Tempurature Per Measurement Point:

140.0 degrees celsius ambient air

# Terminal Type And Quantity:

2 pin

#### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

# Fiig:

A110a0